TOSHIBA GTR Module Silicon N Channel IGBT

# MG100J1ZS40

High Power Switching Applications Motor Control Applications

High input impedance

• High spee :  $t_f = 0.35 \mu s$  (max)

 $t_{rr} = 0.15 \mu s \text{ (max)}$ 

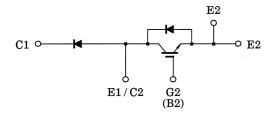
• Low saturation voltage

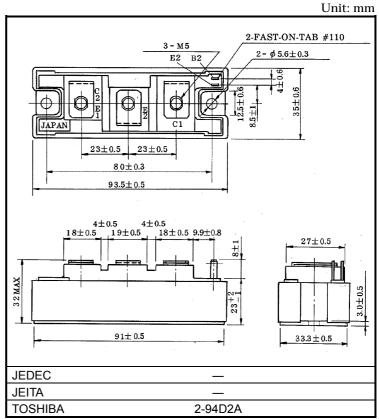
: VCE (sat) = 3.5V (max)

• Enhancement-mode

• The electrodes are isolated from case.

#### **Equivalent Circuit**





Weight: 202g

### **Maximum Ratings (Ta = 25°C)**

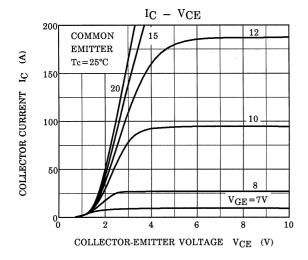
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Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Reverse voltage		V <sub>R</sub>	600	V	
Collector current	DC	IC	100	Α	
	1ms	I <sub>CP</sub>	200		
Forward current	DC	l <sub>F</sub>	100	Α	
	1ms	I <sub>FM</sub>	200		
Collector power dissipation (Tc = 25°C)		P <sub>C</sub>	400	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	<b>−</b> 40 ~ 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)		_	3/3	N·m	

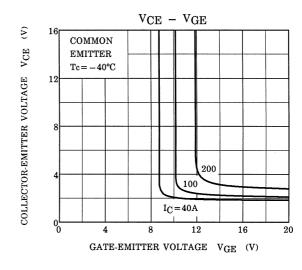
## **Electrical Characteristics (Ta = 25°C)**

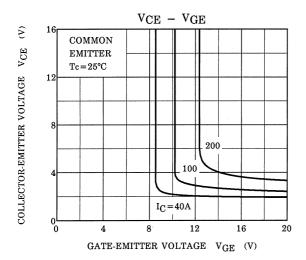
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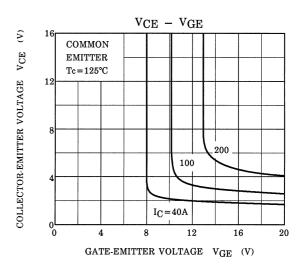
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0	_	_	±500	nA
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 600V, V <sub>GE</sub> = 0	_	_	1.0	mA
Collector-emitter breakdown voltage		V <sub>(BR)</sub> CES	I <sub>C</sub> = 10mA, V <sub>GE</sub> = 0	600	_	_	V
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	I <sub>C</sub> = 100mA , V <sub>CE</sub> = 5A	3.0	_	6.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 100A, V <sub>GE</sub> = 15V	_	2.7	3.5	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz	_	8100	_	pF
Switching time	Rise time	t <sub>r</sub>	15V 24Ω S S S 300V	_	0.30	0.60	μs
	Turn-on time	t <sub>on</sub>		_	0.40	0.80	
	Fall time	t <sub>f</sub>		_	0.18	0.35	
	Turn-off time	t <sub>off</sub>		_	0.60	1.00	
Reverse current		I <sub>R</sub>	V <sub>R</sub> = 600V	_	_	1.0	mA
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 100A, V <sub>GE</sub> = 0	_	2.0	2.70	V
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 100A, V <sub>GE</sub> = -10V, di / dt = 100A / μs	_	0.08	0.15	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor	_	_	0.31	°C/W
			Diode	_	_	0.83	

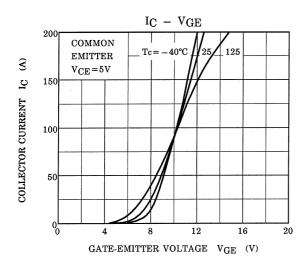
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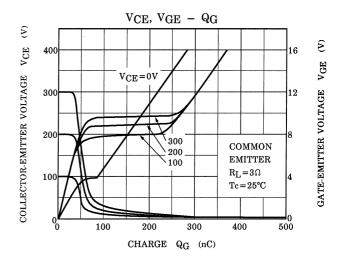




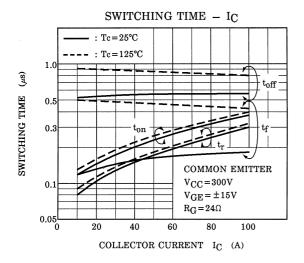


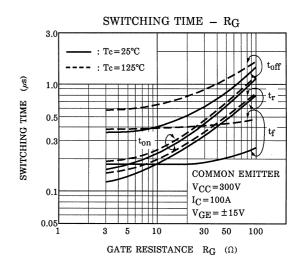


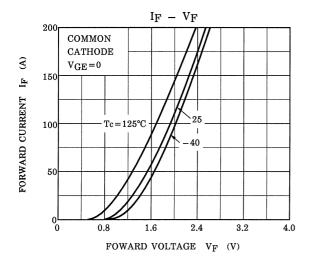


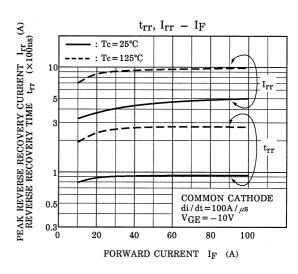


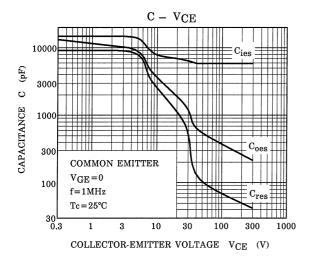
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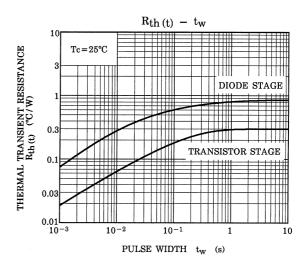




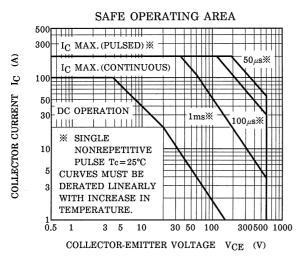


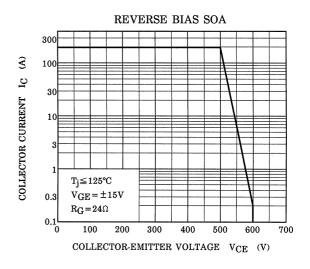






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